


**Features**

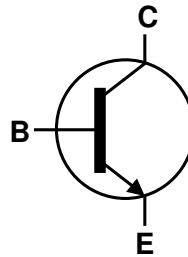
- $BV_{CEO} > 160V$
- Ideal for Low Power Amplification and Switching
- Complementary PNP Type Available (MMBT5401)
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **An automotive-compliant part is available under separate datasheet ([MMBT5551Q](#))**

**Mechanical Data**

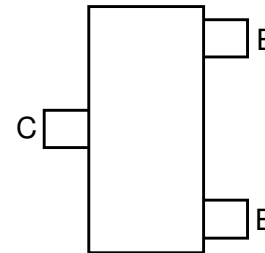
- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 
- Weight: 0.008 grams (Approximate)



Top View



Device Symbol



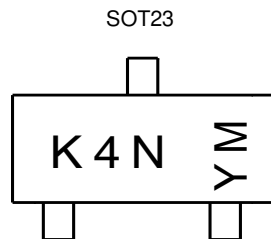
Top View Pin-Out

**Ordering Information** (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
MMBT5551-7-F	SOT23	K4N	7	8	3,000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

**Marking Information**



K4N = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year (ex: K = 2023)  
 M = Month (ex: 9 = September)

Date Code Key

Year	2003	-	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	P	-	K	L	M	N	P	R	S	T	U	V
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

### Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	180	V
Collector-Emitter Voltage	$V_{CEO}$	160	V
Emitter-Base Voltage	$V_{EBO}$	6.0	V
Collector Current - Continuous (Note 5)	$I_C$	600	mA

### Thermal Characteristics (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

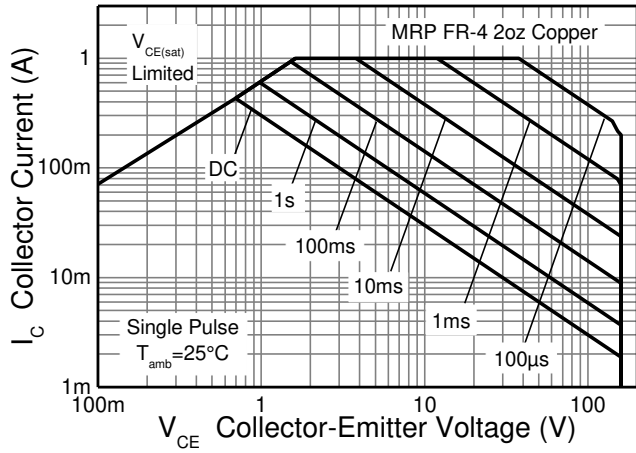
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_D$	300	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

### ESD Ratings (Note 6)

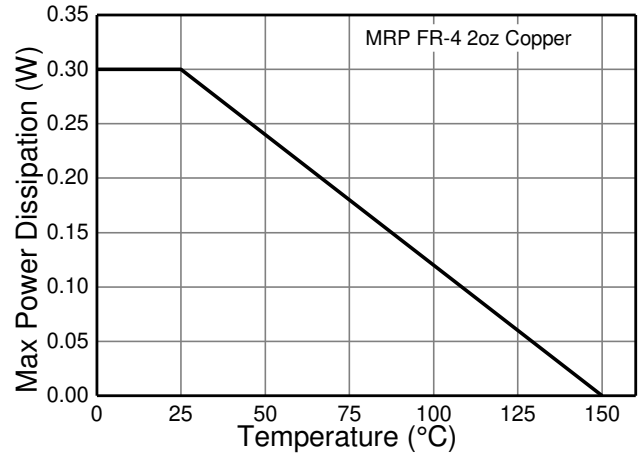
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted on minimum recommended pad layout 2oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

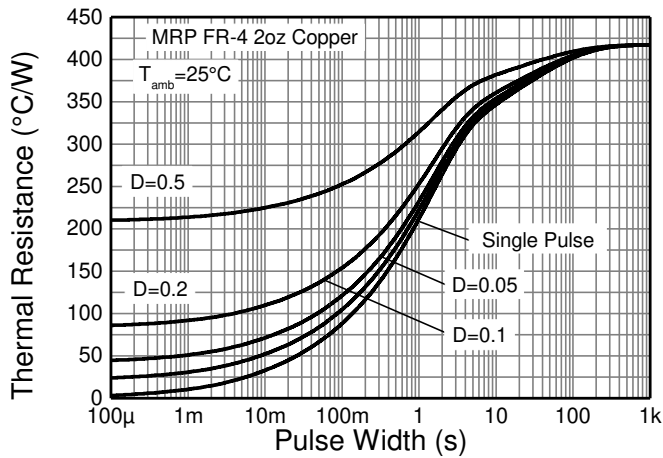
**Thermal Characteristics and Derating Information**



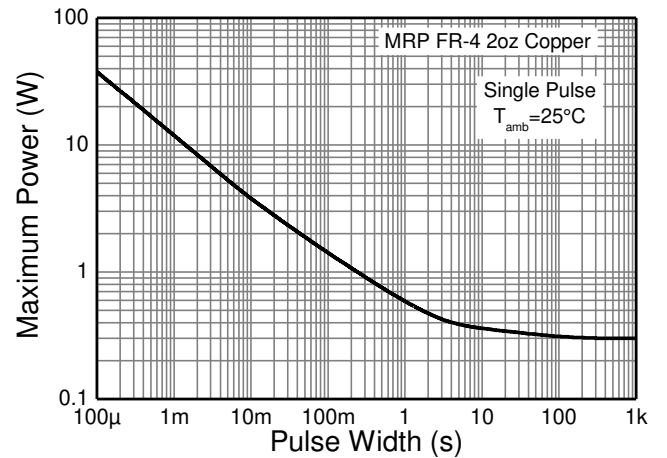
**Figure 1. Safe Operating Area**



**Figure 2. Derating Curve**



**Figure 3. Transient Thermal Impedance**



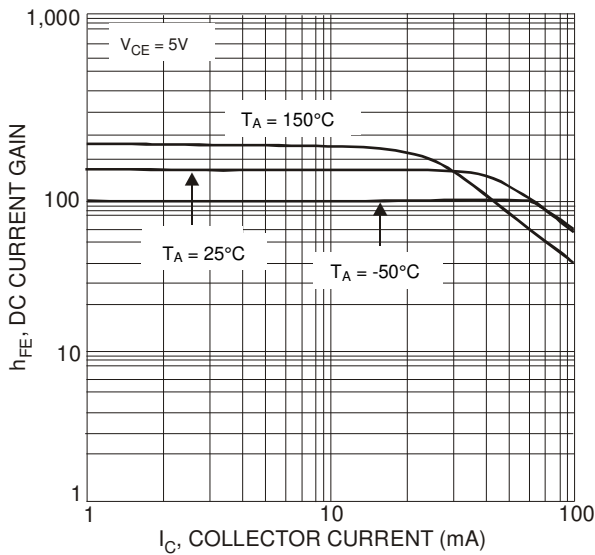
**Figure 4. Pulse Power Dissipation**

**Electrical Characteristics** (@  $T_A = 25^\circ\text{C}$ , unless otherwise specified.)

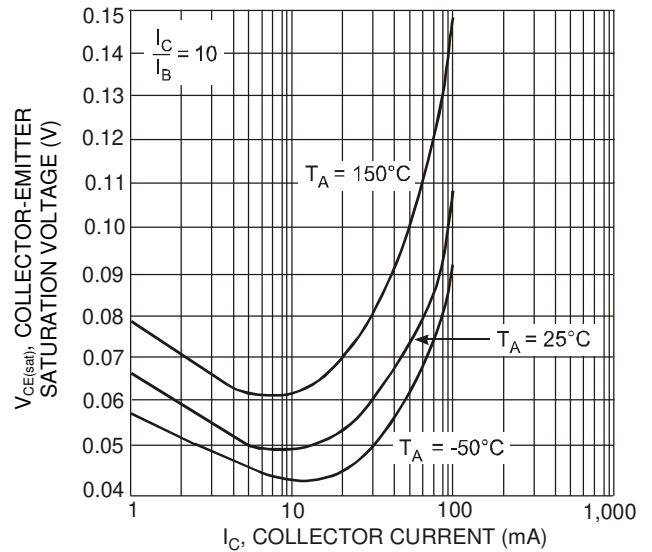
Characteristic	Symbol	Min	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 7)</b>					
Collector-Base Breakdown Voltage	$BV_{CBO}$	180	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$BV_{CEO}$	160	—	V	$I_C = 1\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	6	—	V	$I_E = 10\mu\text{A}$
Collector Cutoff Current	$I_{CBO}$	—	50	nA	$V_{CB} = 120\text{V}$
Emitter Cutoff Current	$I_{EBO}$	—	50	nA	$V_{CB} = 120\text{V}, T_A = +100^\circ\text{C}$
<b>ON CHARACTERISTICS (Note 7)</b>					
DC Current Gain	$h_{FE}$	80 80 30	— 250 —	—	$I_C = 1.0\text{mA}, V_{CE} = 5\text{V}$ $I_C = 10\text{mA}, V_{CE} = 5\text{V}$ $I_C = 50\text{mA}, V_{CE} = 5\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	0.15 0.20	V	$I_C = 10\text{mA}, I_B = 1\text{mA}$ $I_C = 50\text{mA}, I_B = 5\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	—	1 1	V	$I_C = 10\text{mA}, I_B = 1\text{mA}$ $I_C = 50\text{mA}, I_B = 5\text{mA}$
<b>SMALL SIGNAL CHARACTERISTICS</b>					
Output Capacitance	$C_{obo}$	—	6	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$
Small Signal Current Gain	$h_{FE}$	50	250	—	$V_{CE} = 10\text{V}, I_C = 1\text{mA}$ $f = 1\text{kHz}$
Current Gain-Bandwidth Product	$f_t$	100	300	MHz	$V_{CE} = 10\text{V}, I_C = 10\text{mA}$ $f = 100\text{MHz}$
Noise Figure	nf	—	8	dB	$V_{CE} = 5\text{V}, I_C = 200\mu\text{A}$ $R_S = 1\text{k}\Omega, f = 1\text{kHz}$

Note: 7. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

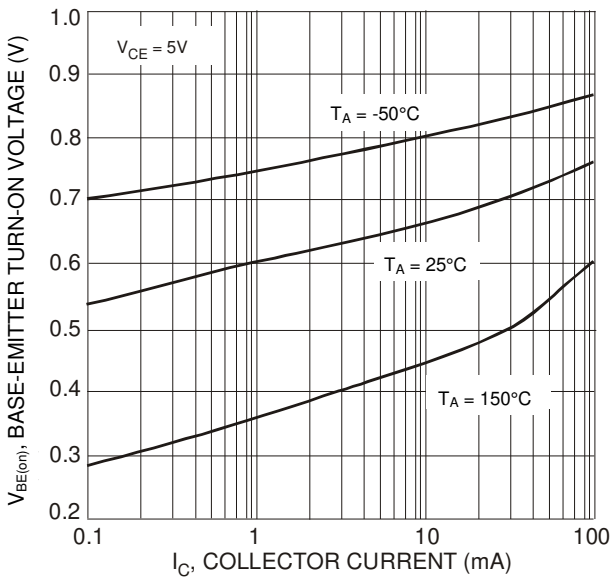
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



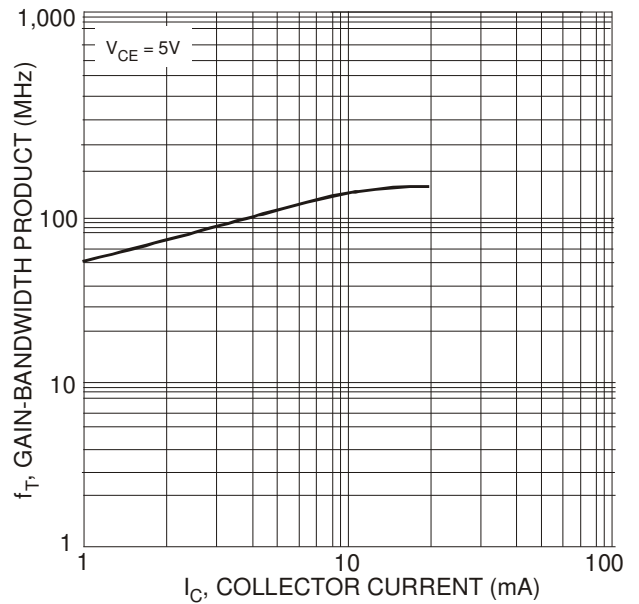
**Figure 5. Typical DC Current Gain vs. Collector Current**



**Figure 6. Typical Collector-Emitter Saturation Voltage vs. Collector Current**



**Figure 7. Typical Base-Emitter Turn-On Voltage vs. Collector Current**

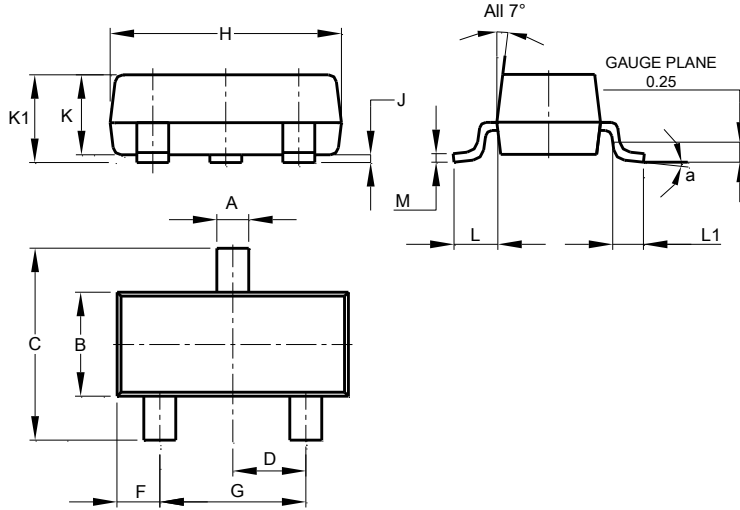


**Figure 8. Typical Gain-Bandwidth Product vs. Collector Current**

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT23**

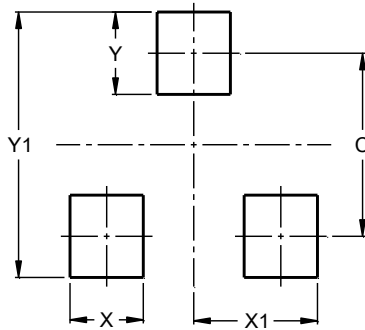


SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT23**



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

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